REV	DESCRIPTION			DATE	PREP	APPD
A	CO-28900			3/26/18	DF/SM	HW
		C • C		TT 1 4	10007	<u> </u>
	🏷 Microsemi.	Specifi	catio	n, Hybri For		J
	Power Matters."	ת יוו	al Store		Output	
	MOUNT HOLLY SPRINGS, PA 17065			dard, LVDS	Output	
	HE RECORD OF APPROVAL FOR THIS MENT IS MAINTAINED ELECTRONICALLY	CODE IDENT NO	SIZE	DWG. NO.		REV
	WITHIN THE ERP SYSTEM	00136	Α	DOC	207139	А
		UNSPECIFIED TOLE	RANCES	: N/A	SHE	ET 1 0F 23

- 1. SCOPE
- 1.1 General. This specification defines the design, assembly and functional evaluation of high reliability, hybrid TCXOs produced by Vectron International. Devices delivered to this specification represent the standardized Parts, Materials and Processes (PMP) Program developed, implemented and certified for advanced applications and extended environments.
- 1.2 Applications Overview. The designs represented by these products were primarily developed for the MIL-Aerospace community. The lesser Design Pedigrees and Screening Options imbedded within DOC207139 bridge the gap between Space and COTS hardware by providing custom hardware with measures of mechanical, assembly and reliability assurance needed for Military, Ruggedized COTS or Commercial environments.

2. APPLICABLE DOCUMENTS

2.1 Specifications and Standards. The following specifications and standards form a part of this document to the extent specified herein. The issue currently in effect on the date of quotation will be the product baseline, unless otherwise specified. In the event of conflict between the texts of any references cited herein, the text of this document shall take precedence.

<u>Military</u> MIL-PRF-55310 MIL-PRF-38534	Oscillators, Crystal Controlled, General Specification For Hybrid Microcircuits, General Specification For
<u>Standards</u> MIL-STD-202 MIL-STD-883	Test Method Standard, Electronic and Electrical Component Parts Test Methods and Procedures for Microelectronics

Vectron International	
QSP-90100	Quality Systems Manual, Vectron International
DOC007131	Identification Common Documents, Materials and Processes, Hi-Rel XO
DOC203982	DPA Specification
QSP-91502	Procedure for Electrostatic Discharge Precautions

3. GENERAL REQUIREMENTS

- 3.1 Classification. All devices delivered to this specification are of hybrid technology conforming to Type 3, Class 2 of MIL-PRF-55310. Devices carry a Class 1C ESDS classification per MIL-PRF-38534 and are marked with a single equilateral triangle at pin 1 per MIL-PRF-55310.
- 3.2 Item Identification. Unique Model Number Series' are utilized to identify device package configurations as listed in Table 1.

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;	Absolute Maximum Ratings.	
	a. Supply Voltage Range (V_{CC}) :	-0.3Vdc to +4.0Vdc
	b. Storage Temperature Range (T _{STG}):	-65°C to +125°C
	c. Junction Temperature (T_J) :	+150C
	d. Lead Temperature (soldering, 10 seconds):	+300°C
	e. Weight	25 grams

- 3.4 Design, Parts, Materials and Processes, Assembly, Inspection and Test.
- 3.4.1 Design. The ruggedized designs implemented for these devices are proven in military and space applications under extreme environments. All designs utilize a 4-point crystal mount. For radiation characteristics, see paragraph 4.1.3. For all Class S and Class B products, components meet the Element Evaluation requirements of MIL-PRF-55310, Appendix B and MIL-PRF-38534, Appendix C. If Design Pedigree Code "E" is chosen, Enhanced Element Evaluation per Appendix A herein will be performed.
- 3.4.1.1 Design and Configuration Stability. Barring changes to improve performance by reselecting passive chip component values to offset component tolerances, there will not be fundamental changes to the design or assembly or parts, materials and processes after first product delivery of that item without written approval from the procuring activity.
- 3.4.1.2 Environmental Integrity. Designs have passed the environmental qualification levels of MIL-PRF-55310. These designs have also passed extended dynamic levels of at least:
 - a. Sine Vibration: MIL-STD-202, Method 204, Condition G (30g pk.)
 - b. Random Vibration: MIL-STD-202, Method 214, Condition II-J (43.92g rms, three minute duration in each of three mutually perpendicular directions)
 - c. Mechanical Shock: MIL-STD-202, Method 213, Condition F (1500g, 0.5ms)
- 3.4.2 Prohibited Parts, Materials and Processes. The items listed are prohibited for use in high reliability devices produced to this specification.
 - a. Gold metallization of package elements without a barrier metal.
 - b. Zinc chromate as a finish.

3.3

- c. Cadmium, zinc, or pure tin external or internal to the device.
- d. Plastic encapsulated semiconductor devices.
- e. Ultrasonically cleaned electronic parts.
- f. Heterojunction Bipolar Transistor (HBT) technology.
- 3.4.3 Assembly. Manufacturing utilizes standardized procedures, processes and verification methods to produce MIL-PRF-55310 Class S / MIL-PRF-38534 Class K equivalent devices. MIL-PRF-38534 Group B Option 1 in-line inspection is included on levels E and R per paragraph 7.1 to further verify lot pedigree. Traceability of all components and production lots are in accordance with MIL-PRF-38534, as a minimum. Tabulated records are provided as a part of the deliverable data package. Devices are handled in accordance with Vectron document QSP-91502 (Procedure for Electrostatic Discharge Precautions).

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- 3.4.4 Inspection. The inspection requirements of MIL-PRF-55310 apply to all devices delivered to this document. Inspection conditions and standards are documented in accordance with the Quality Assurance, ISO-9001 derived system of QSP-90100.
- 3.4.5 Test. The Screening test matrix of Table 4 is tailored for selectable-combination testing to eliminate costs associated with the development/maintenance of device-specific documentation packages while maintaining performance integrity.
- 3.4.6 Marking. Device marking shall be in accordance with the requirements of MIL-PRF-55310.
- 3.4.7 Ruggedized COTS Design Implementation. Design Pedigree "D" devices (see ¶ 5.2) use the same robust designs as the other device pedigrees. They do not include the provisions of traceability or the Class-qualified componentry noted in paragraphs 3.4.3 and 4.1.
- 4. DETAIL REQUIREMENTS
- 4.1 Components
- 4.1.1 Crystals. Cultured quartz crystal resonators are used to provide the selected frequency for the devices. Premium Q swept quartz is standard for all Class S level products because of its superior radiation tolerance. For Class B level products, swept quartz is optional, as required by the customer. In accordance with MIL-PRF-55310, the manufacturer has a documented crystal evaluation program.
- 4.1.2 Passive Components. Passive components will have the same pedigree as the die specified in paragraph 7.1.Where possible, for Design Pedigrees 'E' & 'R', Established Reliability (ER) failure level R and S passive components are employed. Otherwise, all components comply with the Element Evaluation requirements of MIL-PRF-38534 or Enhanced Element Evaluation as specified in Appendix A herein. When used, inductors may be open construction and may use up to 47 gauge wire.
- 4.1.3 Class S Active Devices. Active devices are procured from wafer lots that have passed MIL-PRF-38534 Class K Lot Acceptance Tests for Class S/K devices. Although radiation testing is not performed at the oscillator level, Design Pedigree Codes E and R versions of this TCXO are acceptable for use in environments of up to 100krad (Si) total dose as a result of wafer lot specific RLAT (except varactor diodes) or by analysis of the individual components. The LVDS microcircuit die is sourced in accordance with Standard Microcircuit Drawing 5962F9865107V9A, Class V (MIL-PRF-38535) qualified device. Varactor diodes are considered radiation tolerant by design. A copy of the parts list and materials can be provided for customer review upon request.
- 4.1.3.1 Class B Active Devices. When specified, active devices assembled into Pedigree Codes B and C devices (¶ 5.2a) are procured from wafer lots that have passed MIL-PRF-55310 element evaluations for Class B devices.

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- 4.1.4 Packages. Packages are procured that meet the construction, lead materials and finishes as specified in MIL-PRF-55310. All leads are Kovar with gold plating over a nickel underplate. Package lots are evaluated in accordance with the requirements of MIL-PRF-38534 as applicable.
- 4.1.5 Traceability and Homogeneity. All design pedigrees except option D have active device lots that are homogenous and traceable to the manufacturer's individual wafer. Swept Quartz Crystals are traceable to the quartz bar and the processing details of the autoclave lot, as applicable. All other elements and materials are traceable to their manufacturing lots. Manufacturing lot and date code information shall be recorded, by TCXO serial number, of every component and all materials used in the manufacture of that TCXO. All semiconductors used in the manufacture of a given production lot of TCXOs shall be from the same wafer and have the same manufacturing lot date code. A production lot, as defined by Vectron, is all oscillators that have been kitted and assembled as a single group. After the initial kitting and assembly, this production lot may be divided into multiple sublots to facilitate alignment and test capacity and may be sealed at multiple times within a 13 week window.
- 4.2 Mechanical.
- 4.2.1 Package Outline. Table 1 links each Hi-Rel Standard Model Number of this specification to a corresponding package style. Mechanical Outline information of each package style is found in the referenced Figure. Typical weight for all model numbers is 16 grams.
- 4.2.2 Thermal Characteristics. Because these TCXOs are multichip hybrid designs, the actual θ_{jc} to any one given semiconductor die will vary, but the combined average for all active devices results in a θ_{jc} of approximately 40°C/W. The typical die temperature rise at any one given semiconductor is 2°C to 4°C. Under no circumstance will the junction temperature ever exceed the maximum manufacturer's rated junction temperature when operated within the maximum operating temperature range.
- 4.3 Electrical.
- 4.3.1 Input Power. $3.3 \pm 5\%$ Vdc operation.
- 4.3.2 Temperature Range. Operating range is IAW the chosen temperature stability code.
- 4.3.3 Frequency Tolerance. Temperature stability includes initial accuracy at +25°C (with EFC), load ±10% and supply ±5%.
- 4.3.4 All devices include an External Frequency Control (EFC) pin for the purpose of externally setting each TCXO to its nominal frequency. The EFC shall be accomplished by connecting a resistor or trimmer potentiometer from that Pin to GND. The EFC resistance adjustment range is 0Ω or GND to $20K\Omega$ max with Nominal frequency typically occurring in the $7K\Omega$ to $13K\Omega$ range. Customers will be furnished with the applicable EFC resistor value that can be used to set each individual device within ±0.2 ppm of nominal frequency at time of shipment.

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- 4.3.5 Frequency Aging. Aging limits, when tested in accordance with MIL-PRF-55310 Group B inspection, shall not exceed ±1 ppm for the first year and ±5 ppm for 15 years.
- 4.3.5.1 Frequency Aging Duration Option. By customer request, the Aging test may be terminated after 15 days if the aging projection is less than the specified aging limit. This is a common method of expediting 30-day Aging without incurring risk to the hardware and used quite successfully for numerous customers. It is based on the 'least squares fit' determinations of MIL-PRF-55310 paragraph 4.8.35. Vectron's automated aging systems acquire data every four hours, compared to the minimum MIL-PRF-55310 requirement of once every 72 hours. This makes an extensive amount of data available to perform very accurate aging projections. The delivered data would include the Aging plots projected to 30 days. If the units would not perform within that limit then they would continue to the full 30-day term. Please advise by purchase order text if this may be an acceptable option to exercise as it assists in Production Test planning.
- 4.3.6 Operating Characteristics. See Tables 2 and 3. Waveform measurement points and logic limits are in accordance with Table 2 and Figure 1 herein. Start-up time to reach 80% output amplitude is 10 msec typical and 30 msec maximum.
- 4.3.7 Output Load. See Figure 2 herein.
- 4.3.8 Phase Noise. See Table 2B for typical phase noise.
- 5. QUALITY ASSURANCE PROVISIONS AND VERIFICATION
- 5.1 Verification and Test. Device lots shall be tested prior to delivery in accordance with the applicable Screening Option letter as stated by the 16th character of the part number. Table 5 tests are conducted in the order shown and annotated on the appropriate process travelers and data sheets of the governing test procedure. For devices that require Screening Options that include MIL-PRF-55310 Group A Testing, the Post-Burn-In Electrical Test and the Group A Electrical Test are combined into one operation.
- 5.1.1 Screening Options. The Screening Options, by letter, are summarized as:
 - (K) Modified MIL-PRF-38534 Class K Screening, Group A QCI and 30-day aging
 - (S) MIL-PRF-55310 Class S Screening, Groups A & B QCI
 - (C) Modified MIL-PRF-55310 Class B Screening, Groups A & B QCI
 - (B) MIL-PRF-55310 Class B Screening, Groups A & B QCI
 - (X) Engineering Model (EM)
- 5.2 Optional Design, Test and Data Parameters. The following is a list of design, assembly, inspection and test options that can be added by purchase order request.

a. Design Pedigree (choose one as the 5th character in the part number):

- (E) Class S components, Enhanced Element Evaluation, Swept Quartz
- (**R**) Class S components, Swept Quartz

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- (B) Class B components, Swept Quartz
- (C) Class B components, Non-Swept Quartz
- (D) COTS components, Non-Swept Quartz
- b. Input Voltage as the 15th character
- c. Frequency-Temperature Slew Test
- d. Radiographic Inspection
- e. Group C Inspection: MIL-PRF-55310 (requires 8 destruct specimens)
- f. Group C Inspection: MIL-PRF-38534, Table C-Xc, Periodic Inspection (requires 10 destruct specimens 5 pc. [SG 1(5/0), SG 3(3/0)], 5 pc. SG 2 (5/0). Subgroup 1 fine leak test to be performed per MIL-STD-202, Method 112, Condition C.
- g. Qualification: In accordance with EEE-INST-002, Section C4, Table 3, Level 1 or 2 (requires 11 destruct specimens)
- h. Qualification: In accordance with MIL-PRF-55310, Table IV (requires 11 destruct specimens).
- i. Internal Water-Vapor Content (RGA) samples and test performance
- j. MTBF Reliability Calculations
- k. Worst Case/Derating Analysis
- 1. Deliverable Process Identification Documentation (PID)
- m. Customer Source Inspection (pre-cap / final)
- n. Destruct Physical Analysis (DPA): MIL-STD-1580 with exceptions as specified in Vectron DOC203982.
- o. High Resolution Digital Pre-Cap Photographs (20 Megapixels minimum)
- p. Hot solder dip of leads with Sn63/Pb37 solder prior to shipping.
- 5.2.1 NASA EEE-INST-002. A combination of design pedigrees E or R along with Screening option S and Group C Inspection in accordance with MIL-PRF-55310, meet the requirements of Level 1 device reliability. A combination of design pedigrees B or C along with screening option C and Group C Inspection in accordance with MIL-PRF-55310, meet the requirements of Level 2 device reliability.
- 5.3 Test Conditions. Unless otherwise stated herein, inspections are performed in accordance with those specified in MIL-PRF-55310. Process travelers identify the applicable methods, conditions and procedures to be used. Examples of electrical test procedures that correspond to MIL-PRF-55310 requirements are shown in Table 3.
- 5.4 Deliverable Data. The manufacturer supplies the following data, as a minimum, with each lot of devices:
 - a. Completed assembly and screening lot travelers, including rework history and Certificate of Conformance.
 - b. Electrical test variables data, identified by unique serial number.
 - c. Frequency-Temperature Slew plots, Radiographic data, Group C data and RGA data as required by purchase order.
 - d. Traceability, component LAT, enclosure LAT and RLAT (if specifically requested on the purchase order).
- 5.5 Discrepant Material. All MRB authority resides with the procuring activity.

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5.6 Failure Analysis. Any catastrophic failure (no output, no input current) at Post Burn-In or after will be evaluated for root cause. The customer will be notified after occurrence and upon completion of the evaluation.

6. PREPARATION FOR DELIVERY

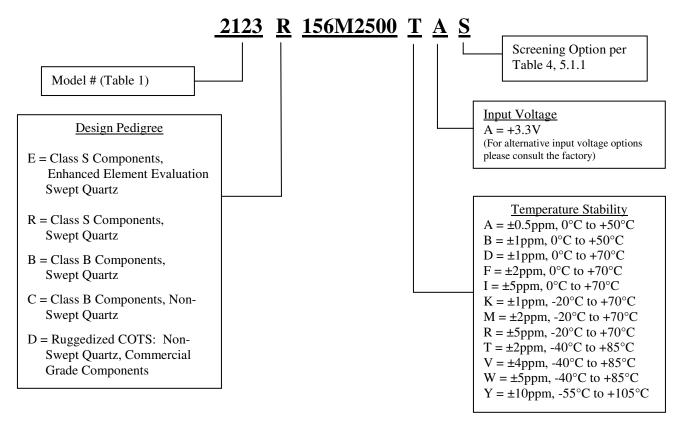
6.1 Packaging. Devices will be packaged in a manner that prevents handling, ESD and transit damage during shipping.

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
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7. ORDERING INFORMATION

7.1 Ordering Part Number. The ordering part number is made up of an alphanumeric series of 16 characters. Design-affected product options, identified by the parenthetic letter on the Optional Parameters list (¶ 5.2a and b), are included within the device part number.

The Part Number breakdown is described as:



- 7.1.1 Model Number. The device model number is the four (4) digit number assigned to a corresponding package and output combination per Table 1.
- 7.1.2 Design Pedigree. Class S designs correspond to letters "E" and "R" and are described in paragraph 5.2a. Class B variants correspond to either letter "B" or "C" and are described in paragraph 5.2a. Ruggedized COTS, using commercial grade components, correspond to letter "D".
- 7.1.2.1 Input Voltage. Voltage is the 15th character. Voltage availability is dependent on platform.
- 7.1.3 Output Frequency. The nominal output frequency is expressed in the format as specified in MIL-PRF-55310 utilizing eight (8) characters.
- 7.1.4 Screening Options. The 16th character is the Screening Option selected from Table 4.

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7.2 Optional Design, Test and Data Parameters. Test and documentation requirements above that of the standard high reliability model shall be specified by separate purchase order line items (as listed in ¶ 5.2c thru p).

MODEL #	PACKAGE	OUTPUT (LVDS)	MECHANICAL OUTLINE AND I/O CONNECTIONS
2123	24 Lead Flatpack	Single Pair	Figure 3
2223 <u>2</u> /	24 Lead Flatpack	Single Pair	Figure 4
2133	24 Lead Flatpack	Dual Pair	Figure 5
2233 <u>2</u> /	24 Lead Flatpack	Dual Pair	Figure 6

- <u>1</u>/. All unassigned pins have no internal connections or ties and may be externally connected to GND by the customer.
- 2/. Model 2223 and 2233 represent lead formed versions.

TABLE 1 - Item Identification and Package Outline

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
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Models 2123, 2223, 2133, 2233										
Supply Voltage:	Supply Voltage: +3.3V ±5%									
Single-Ended Out	Single-Ended Output Voltage (+V _{OD} or -V _{OD}): 250mV to 450mV									
Differential Output	Differential Output Voltage (V _{Diff}): 500mV to 900mV									
Offset Voltage (V	Offset Voltage (V _{os}): 1.125V to 1.450V									
Frequency	Max Current	Max Current	Max t _r /t _f	Duty Cycle						
Range	(Vcc Osc Input)	(Vcc LVDS Chip)	(ps)	(%)						
(MHz)	(mA)	(mA)	<u>2</u> /	<u>2</u> /						
	<u>1</u> /	<u>1</u> /								
12 - 200	25	20	600	40 to 60						

<u>1</u>/. Current measurements are taken at maximum supply voltage.

2/. Waveform measurement points and logic limits are in accordance with Figure 1.

 TABLE 2 - Electrical Performance Characteristics

Frequency	Typical Period Jitter	Typical Period Jitter	Typical Phase Jitter
(MHz)	1 sigma	peak-to-peak	12kHz to 20MHz
	(ps)	(ps)	(ps)
136	3.5	24	0.15

TABLE 2A – Typical Jitter Performance

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TABLE 2B – Typical Phase Noise at 136 MHz

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
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OPERATION LISTING	REQUIREMENTS AND CONDITIONS	VECTRON TEST
Lugart Cramont (a a load)	MIL DDE 55210 Dame 4.9.5.1	PROCEDURE
Input Current (no load)	MIL-PRF-55310, Para 4.8.5.1	GR-51681
Initial Accuracy @ Ref. Temp.	MIL-PRF-55310, Para 4.8.6	GR-51596
Output Logic Voltage Levels	MIL-PRF-55310, Para 4.8.21.3	GR-51597
Rise and Fall Times	MIL-PRF-55310, Para 4.8.22	GR-51599
Duty Cycle	MIL-PRF-55310, Para 4.8.23	GR-51601
Overvoltage Survivability	MIL-PRF-55310, Para 4.8.4	GR-37269
Initial Freq. – Temp. Accuracy	MIL-PRF-55310, Para 4.8.10.1	DOC005199
Freq. – Voltage Tolerance	MIL-PRF-55310, Para 4.8.14	DOC005199
Start-up Time (fast/slow start)	MIL-PRF-55310, Para 4.8.29	GR-61352

TABLE 3 - Electrical Test Parameters

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
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	S	CREENING & TESTIN	G OPTIONS		
Option Code	K	S	С	В	X
Screening (By Class Similarity)	Mil-PRF-38534 Class 'K'	Mil-PRF-55310 Class 'S'	Mil-PRF-55310 Class 'B' modified	Mil-PRF-55310 Class 'B'	Engineering Model (EM)
Non-Destruct Wire Bond Pull	100%	100%	N/A	N/A	N/A
Internal Visual	M883, Method 2017 for Class 'K'	M883, Method 2017 for Class 'K'	M883, Method 2017 for Class 'H'	M883, Method 2017 for Class 'H'	M883, Method 2017 for Class 'H'
Stabilization Bake	48 hrs min @ +150°C	48 hrs min @ +150°C	48 hrs min @ +150°C	48 hrs min @ +150°C	24 hrs min @ +150°C
Thermal Shock	M883, Method 1011, TC 'A'	M883, Method 1011, TC 'A'	N/A	N/A	N/A
Temperature Cycling	M883, Method 1010, TC 'B'	M883, Method 1010, TC 'B'	M883, Method 1010, TC 'B'	M883, Method 1010, TC 'B'	N/A
Constant Acceleration	M883, Method 2001, TC 'A' (5000 g, Y1 Axis only)	M883, Method 2001, TC 'A' (5000 g, Y1 Axis only)	M883, Method 2001, TC 'A' (5000 g, Y1 Axis only)	M883, Method 2001, TC 'A' (5000 g, Y1 Axis only)	N/A
PIND	M883, Method 2020, TC 'B'	M883, Method 2020, TC 'B'	M883, Method 2020, TC 'B'	N/A	N/A
Electrical Test Frequency, Output levels, Input Current	@ +25°C only	@ +25°C only	@ +25°C only	@ +25°C only	@ +25°C only
1 st Burn-In (Powered with load)	+125°C for 160 hours	+125°C for 240 hours	+125°C for 160 hours	+125°C for 160 hours	N/A
Electrical Test Frequency, Output levels, Input Current	@ +25°C & Temp Extremes	@ +25°C & Temp Extremes	@ +25°C & Temp Extremes	@ +25°C & Temp Extremes	N/A
2 nd Burn-In (Powered with load)	+125°C for 160 hours	N/A	N/A	N/A	N/A
Electrical Test Frequency, Output levels, Input Current	@ +25°C & Temp Extremes	N/A	N/A	N/A	N/A
PDA	2% applies to Input Current @ +25°C Post 2 ND Burn-in Electrical Test	2% applies to Input Current @ +25°C	10% applies to Input Current @ +25°C	10% applies to Input Current @ +25°C	N/A
Radiographic	M883, Method 2012	M883, Method 2012	M883, Method 2012	N/A	N/A
Seal Test (fine & gross)	100%	100%	100%	100%	100%
Group 'A' Inspection	100%	100%	Sample per Mil-PRF-55310	Sample per Mil-PRF-55310	N/A
Group 'B' Inspection (30 day Aging @ +70°C)	100%	100%	Sample per Mil-PRF-55310	Sample per Mil-PRF-55310	N/A

TABLE 4 Screening & Test Matrix

-						
SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136		N/A	DOC207139	Α	14

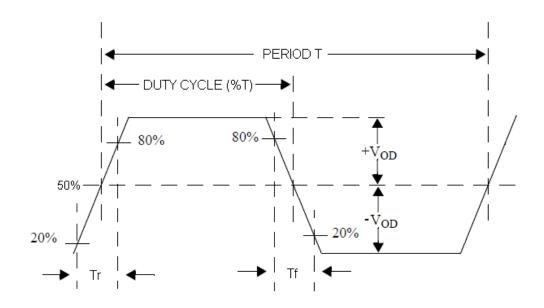
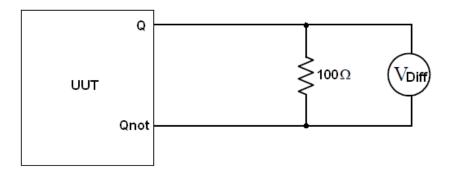


Figure 1 Differential Output Waveform





CODE IDENT NO		UNSPECIFIED TOLER ANCES	DWG NO	PEV	SHEET
	THIRD ANGLE FROSECTION	endrieten mer robendriveee	DWO NO.	KLV.	STILLT
00126	_(⊕) +	NT/A	DOC207120	٨	15
00130	↓ □	IN/A	DUC20/139	A	15
	CODE IDENT NO. 00136			Divolito.	The Action of th

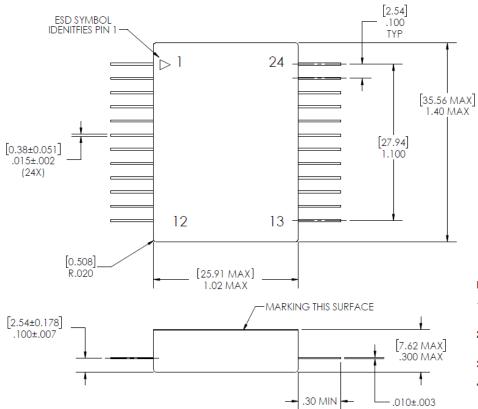


FIGURE 3 Single LVDS pair Models 2123 Package Outline PIN CONNECTIONS

1 = EXTERNAL FREQUENCY CONTROL

2 THRU 11 = NO INTERNAL CONNECTION

12 = GND & CASE GND

13 = OUTPUT Q

14 = OUTPUT Q

15 = Vcc for LVDS Chip

16 = ENABLE Floating or Logic '0' Enables both Outputs Logic '1' Disables both Outputs

17 THRU 23 = NO INTERNAL CONNECTION

24 = Vcc for OSCILLATOR CIRCUIT

NOTES

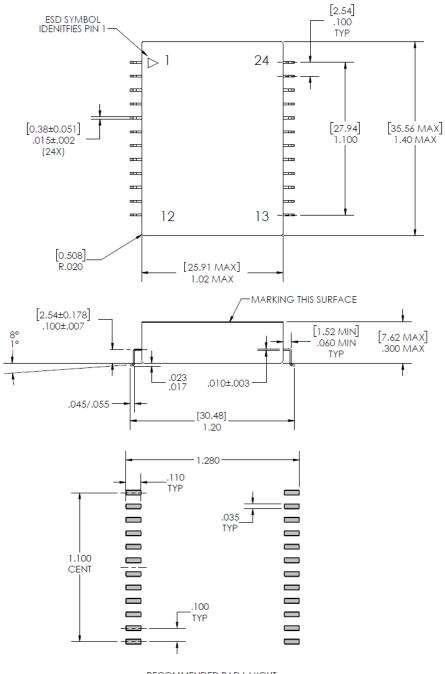
1. PIN NUMBERS ARE FOR REFERENCE ONLY AND DO NOT APPEAR ON THE UNIT

2. 'NO INTERNAL CONNECTION' PINS MAY BE EXTERNALLY GROUNDED.

3. ENCLOSURE MATERIAL: KOVAR

4. ENCLOSURE PLATING: GOLD OVER NICKEL

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136		N/A	DOC207139	А	16



PIN CONNECTIONS

- 1 = EXTERNAL FREQUENCY CONTROL
- 2 THRU 11 = NO INTERNAL CONNECTION
- 12 = GND & CASE GND
- 13 = OUTPUT Q
- 14 = OUTPUT <u>Q</u>
- 15 = Vcc for LVDS Chip

16 = ENABLE Floating or Logic '0' Enables both Outputs

- Logic '1' Disables both Outputs 17 THRU 23 = NO INTERNAL CONNECTION
- 24 = Vcc for OSCILLATOR CIRCUIT

NOTES

- 1. PIN NUMBERS ARE FOR REFERENCE ONLY AND DO NOT APPEAR ON THE UNIT
- 2. 'NO INTERNAL CONNECTION' PINS MAY BE EXTERNALLY GROUNDED.
- 3. ENCLOSURE MATERIAL: KOVAR
- 4. ENCLOSURE PLATING: GOLD OVER NICKEL

RECOMMENDED PAD LAYOUT FOR MOUNTING FORMED PACKAGE

FIGURE 4 Single pair LVDS

Models 2223 Package Outline

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-]	N/A	DOC207139	Α	17

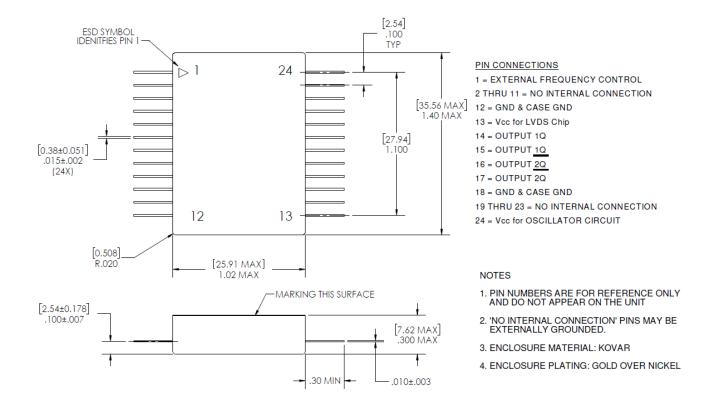
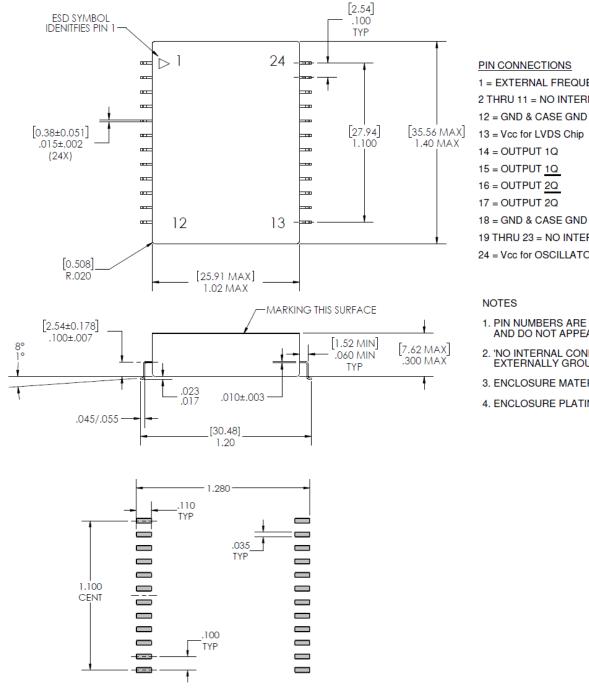


FIGURE 5 Dual pair LVDS Models 2133 Package Outline

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-J	N/A	DOC207139	А	18



1 = EXTERNAL FREQUENCY CONTROL 2 THRU 11 = NO INTERNAL CONNECTION

- 13 = Vcc for LVDS Chip
- 14 = OUTPUT 1Q
- 15 = OUTPUT 1Q
- 16 = OUTPUT 2Q
- 17 = OUTPUT 2Q
- 18 = GND & CASE GND
- 19 THRU 23 = NO INTERNAL CONNECTION
- 24 = Vcc for OSCILLATOR CIRCUIT

NOTES

- 1. PIN NUMBERS ARE FOR REFERENCE ONLY AND DO NOT APPEAR ON THE UNIT
- 2. 'NO INTERNAL CONNECTION' PINS MAY BE EXTERNALLY GROUNDED.
- 3. ENCLOSURE MATERIAL: KOVAR
- 4. ENCLOSURE PLATING: GOLD OVER NICKEL

RECOMMENDED PAD LAYOUT FOR MOUNTING FORMED PACKAGE

FIGURE 6 Dual pair LVDS

Models 2233 Package Outline

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-]	N/A	DOC207139	Α	19

Appendix A

ENHANCED ELEMENT EVALUATION

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-J	N/A	DOC207139	Α	20

Subgroup	Class	Test	Mil-S	TD-883	Quantity	Mil-PRF- 38534 Reference
	K		Method	Condition	(accept number)	Paragraph
1	X	Element Electrical A. May perform at wafer level B. All failures shall be removed from the lot C. Perform at room ambient			100%	C.3.3.1
2	Х	Element Visual	2010		100%	C.3.3.2
3	Х	Internal Visual	2010		10(0) or 22(0) (See Notes 1 & 2)	C.3.3.3 C.3.3.4.2
4	X	Temperature Cycling	1010	С		C.3.3.3
	X	Mechanical Shock	2002	B, Y1	10(0)	
		or Constant Acceleration	2001	direction 3,000 G, Y1 direction	22(0) (See Notes 1 & 2)	
	Х	Interim Electrical				C.3.3.4.3
	X	Burn-In	1015	240 hours minimum at +125°C		
	Х	Post Burn-In Electrical				C.3.3.4.3
	Х	Steady State Life	1005]	
	Х	Final Electrical				C.3.3.4.3
5	Х	Wire Bond Evaluation	2011		10(0) wires or 20(1) wires	C.3.3.3 C.3.3.5
6	X	SEM	2018		See method 2018 & Note 2	C.3.3.6

MICROCIRCUIT ENHANCED ELEMENT EVALUATION

NOTES:

- 1. Subgroups 3, 4, & 5 shall be performed on a sample of 10 die if the wafer lot is from a QPL/QML line. If the die are from commercial wafer lots, then the sample size shall be 22 die. Die from QPL/QML wafers not meeting the QPL/QML requirements and downgraded to commercial grade shall not be used.
- 2. Subgroups 3, 4 & 5 shall be performed in the order listed in Table 1. Subgroup 6 may be performed at any time.

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-]	N/A	DOC207139	A	21

Subgroup	Class	Test	Mil-ST		Quantity	Mil-PRF- 38534 Reference
	K		Method	Condition	(accept number)	Paragraph
1	X	Element Electrical A. May perform at wafer level B. All failures shall be removed from the lot		Perform at room ambient	100%	C.3.3.1
2	X	Element Visual	2069, 2070, 2072, 2073		100%	C.3.3.2
3	X	Internal Visual	2069, 2070, 2072, 2073, 2074		10(0) or 22(0) (Notes 1 & 2)	C.3.3.3 C.3.3.4.2
4	Х	Temperature Cycling	1051	С		C.3.3.3
	Х	Surge Current (when applicable)	4066	A or B as specified		
	X	Constant Acceleration	2006 2001	Y1 direction 20,000 G / 10,000 G for	10(0) 22(0) (See Notes 1 & 2)	
	X	Interim Electrical		$Pd \ge 10W$		C.3.3.4.3
	X	High Temperature Reverse Bias (HTRB)	1039 1042 1038	A B A		0.3.3.4.3
	x	Interim Electrical & Delta		Complete Within 16 hrs of HTRB completion		
	X	Burn-In 240 hours	1039, 1042 1038 1040	B,A B		
	Х	Post Burn-In Electrical				C.3.3.4.3
	x	Steady State Life 1000 hours or equivalent per MIL-PRF-19500	1026 1037 1042 1048			
	Х	Final Electrical				C.3.3.4.3
5	X	Wire Bond Evaluation	2011		10(0) wires or 20(1) wires	C.3.3.3 C.3.3.5
6	Х	SEM	2018 2077		See method 2018 or 2077 & Note 2	C.3.3.6

SEMICONDUCTOR ENHANCED ELEMENT EVALUATION

NOTES:

- 1. Subgroups 3, 4, & 5 shall be performed on a sample of 10 die if the wafer lot is from a QPL/QML line. If the die are from commercial wafer lots, then the sample size shall be 22 die. Die from QPL/QML wafers not meeting the QPL/QML requirements and downgraded to commercial grade shall not be used.
- 2. Subgroups 3, 4 & 5 shall be performed in the order listed in Table 1. Subgroup 6 may be performed at any time.

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136		N/A	DOC207139	Α	22

Part Type	Test	Requirements Paragraph	Sample Size	Allowable Rejects
Ceramic capacitors (Produc	tion lot definition shall be pe	r M55681 or M123 for	chips, or M49470 T-leve	el for stacks)
M55681 FRL S or M123 (chips)	N/A	N/A	N/A	N/A
DSCC Dwg COTS (chips)	Ultrasonic scan or CSAM	M123	100%	N/A
	Group A	M123	M123	M123
	Group B, Subgroups 1 & 2	M123	M123	M123
T-level M49470 (stacked)	N/A	N/A	N/A	N/A
General purpose M49470,	Ultrasonic scan or CSAM	M49470 for T-level	100%	N/A
DSCC dwg or COTS	Group A	M49470 for T-level	M49470 for T-level	M49470 for T-level
(stacked)	Group B, Subgroups 2, 4 & 5b	M49470 for T-level	M49470 for T-level	M49470 for T-level
Tantalum Chip Capacitors minimum Weibull C and surg	ge current option C. Production			up A in M55365 with
M55365	Group A (Weibull C minimum with surge current option C)	M55365	M55365	M55365
DSCC Dwg, COTS	Group A (Weibull C minimum with surge current option C)	M55365	M55365	M55365
	Group C	M55365	M55365	M55365
Resistor Chips (Note: Gluin without extensive design/proper M55342).				
M55342 FRL R or S	N/A	N/A	N/A	N/A
DSCC Dwg, COTS	Group A	M55342 for T-level	M55342 for T-level	M55342 for T-level
	Group B	M55342 for T-level	M55342 for T-level	M55342 for T-level
Inductors (See Paragraph	4.1.2)			
Magnetics, Closed Construct			tors, coils) (Note: Stacl	king magnetics shall be
qualified and the effects of the cycling plus electrical measures shall conform to MIL-STD-9 Magnetics, Open Construction magnetic core. These parts measurements and visual insp	are fully visually inspectable	up A of Mil-Std-981. npotted self-leaded par	Design, workmanship a ts consisting of magnet	and materials/processes
cycling plus electrical measu shall conform to MIL-STD-9 Magnetics, Open Construction magnetic core. These parts	are fully visually inspectable	up A of Mil-Std-981. npotted self-leaded par	Design, workmanship a ts consisting of magnet	and materials/processes

PASSIVE COMPONENTS ENHANCED ELEMENT EVALUATION

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-]	N/A	DOC207139	Α	23